

# An Interlaboratory Study on the Stability of All-Printable Hole Transport Material–Free Perovskite Solar Cells

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Comparisons between different laboratories on long-term stability analyses of perovskite solar cells (PSCs) is still lacking in the literature. This work presents the results of an interlaboratory study conducted between five laboratories from four countries. Carbon-based PSCs are prepared by screen printing, encapsulated, and sent to different laboratories across Europe to assess their stability by the application of three ISOS aging protocols: (a) in the dark (ISOS-D), (b) under simulated sunlight (ISOS-L), and (c) outdoors (ISOS-O). Over 1000 h stability is reported for devices in the dark, both at room temperature and at 65 °C. Under continuous illumination at open circuit, cells survive only for few hours, although they recover after being stored in the dark. Better stability is observed for cells biased at maximum power point under illumination. Finally, devices operate in outdoors for 30 days, with minor degradation, in two different locations (Barcelona, Spain and Paola, Malta). The findings demonstrate that open-circuit conditions are too severe for stability assessment and that the diurnal variation of the photovoltaic parameters reveals performance to be strongly limited by the fill factor, in the central hours of the day, due to the high series resistance of the carbon electrode.

## 1. Introduction


The efficiency of hybrid organic–inorganic metal halide perovskite solar cells (PSCs)<sup>[1,2]</sup> has rapidly reached up to over 25% in the past few years.<sup>[3]</sup> Nonetheless, several factors have been demonstrated to induce PSC degradation, e.g., light,<sup>[4,5]</sup> temperature,<sup>[6,7]</sup> oxygen,<sup>[8,9]</sup> humidity,<sup>[10,11]</sup> and electrical bias,<sup>[12–14]</sup> limiting the operational stability of such efficient devices and thus their commercialization.

In the wide range of possible device architectures and material combinations demonstrated so far for PSCs, carbon-based hole transport material (HTM)-free PSCs (C-PSC) are one of the most promising, in terms of ease of manufacture,<sup>[15]</sup> environmental impact,<sup>[16]</sup> and long-term stability.<sup>[17]</sup>

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Correction added on 23 February 2021, after first online publication: The copyright line was changed.

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Consisting of an all-printable triple mesoscopic stack, i.e., titania (TiO<sub>2</sub>) electron transport layer, zirconia (ZrO<sub>2</sub>) insulating layer, and carbon-based back electrode, they show great potential as a low-cost photovoltaic (PV) technology for industrial production. Efforts have been concentrated to improve the manufacturing process,<sup>[18–23]</sup> and large C-PSC modules have already been reported by different groups, with power conversion efficiency (PCE) ranging between 6% and 11%.<sup>[17–19,23,24]</sup>

When considering small cells ( $\leq 1 \text{ cm}^2$  of active area), C-PSCs lag behind other PSC architectures that have recently exceeded 25% efficiency.<sup>[3]</sup> Regardless, a certified PCE as high as 12.84% has been reported for the methylammonium lead iodide (MAPI)-infiltrated TiO<sub>2</sub>/ZrO<sub>2</sub>/C stack,<sup>[15]</sup> whereas the record PCE ranges between 16% for a triple cation perovskite absorber, infiltrated in the same triple mesoscopic structure,<sup>[25]</sup> and 17% for an inverted structure, also endowed with a triple cation perovskite plus a nickel oxide layer between the insulator and the carbon electrode.<sup>[26]</sup>

An important milestone in their development was the addition of 5-AVAI (5-ammonium valeric acid iodide) to the perovskite precursors' solution: it has been proved to induce the formation of a peculiar multidimensional 2D/3D perovskite junction, i.e., AVA-MAPI, featuring both the enhanced stability of 2D perovskites and the broad absorption and excellent charge transport of 3D MAPI.<sup>[17,27]</sup> The additive located at grain boundaries also passivates surface defects, limiting the oxygen-induced degradation.<sup>[28]</sup> While lower in efficiency, C-PSC devices, endowed with AVA-MAPI perovskite, have demonstrated remarkable stability under illumination, both indoor at 1 sun, AM1.5 ( $>1 \text{ year}^{[17]}$ ), and outdoor (30 days, in Wuhan, China;<sup>[19]</sup> 2136 h, i.e., 89 days, near Beijing, China<sup>[29]</sup>). In all these reports, assessment of the stability was conducted by the manufacturer, which is common practice in this field, rather than through independent verification from an alternate laboratory. Round robin stability studies on PSC are still limited; however, as the technology matures, such studies will provide vital insight into testing protocols and variability in the stability from different testing approaches.<sup>[13,30–32]</sup>

This work assesses the stability of C-PSCs under a variety of conditions and involves measurements at five independent laboratories across Europe (UK, Italy, Spain, and Malta) for measurements and characterization, following the example set at the International Summits on Organic Photovoltaic Stability (ISOS) by the Organic Photovoltaics (OPV) community, who has promoted and widely participated in round robins and interlaboratory studies.<sup>[33–36]</sup>

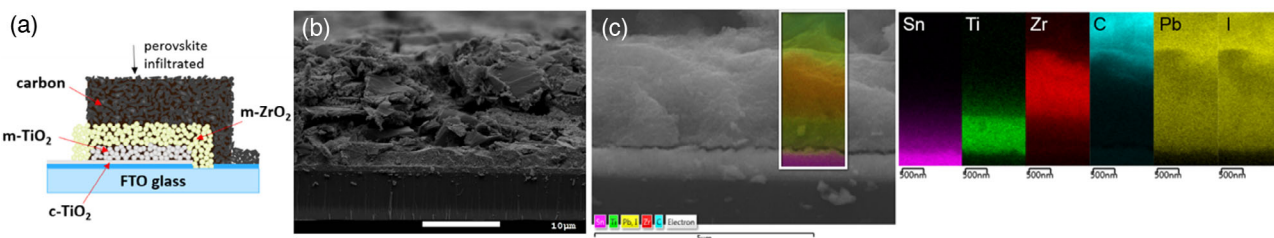
C-PSCs were manufactured by screen printing and infiltrated with AVA-MAPI solution at a single manufacturing site, encapsulated, and then sent to different laboratories for characterization in accordance with three ISOS protocols:<sup>[37]</sup> in the dark (ISOS-D), under simulated sunlight (ISOS-L), and outdoors (ISOS-O). Although this work was conducted in line with previous ISOS guidelines, which were established for OPV,<sup>[37]</sup> it aligns with the new ISOS consensus stability standards for PSCs that has been published very recently.<sup>[38]</sup> Additional material characterization measurements were performed to better understand the behavior of the devices.

## 2. Results and Discussion

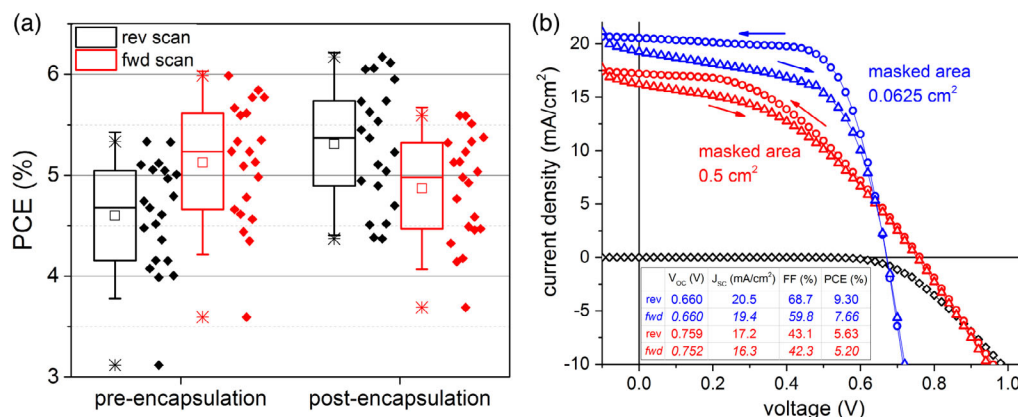
C-PSCs used in this work consisted of a compact TiO<sub>2</sub> (c-TiO<sub>2</sub>), deposited by spray pyrolysis on an fluorine-doped tin oxide (FTO) glass covered, and three printed mesoporous layers: titania (m-TiO<sub>2</sub>), zirconia (m-ZrO<sub>2</sub>), and carbon (**Figure 1a**). While the former two layers have similar porosity and are hardly distinguishable, the over 10  $\mu\text{m}$ -thick carbon layer is made of both large graphite flakes and fine carbon black particles, as shown by the cross-sectional scanning electron microscopy (SEM) (Figure 1b). The energy-dispersive X-ray spectroscopy (EDX) images (Figure 1c) reveal that TiO<sub>2</sub> and ZrO<sub>2</sub> layers are about 0.8 and 1.2  $\mu\text{m}$ , respectively, and according to the uniform distribution of lead and iodine elements, the perovskite is infiltrated throughout the stack.

### 2.1. Photovoltaic Performance of As-Prepared Devices

$J$ - $V$  measurements on 21 devices, masked to 0.5  $\text{cm}^2$  active area, returned a spread distribution of PCE values both prior to (around 4.6% in average—reverse scan) and after encapsulation (around 5.4% in average—reverse scan), but no remarkable degradation, as shown in **Figure 2a**. A slight improvement in performance, primarily from changes in open-circuit voltage ( $V_{\text{OC}}$ ) and fill factor (FF), was noted after encapsulation along with a decrease in  $J_{\text{SC}}$  (Figure S1, Supporting Information). As reported earlier, cells with the same structure (TiO<sub>2</sub>/ZrO<sub>2</sub>/C) and more conductive carbon electrode, infiltrated with the same perovskite, can deliver up to 12% PCE on a masked area of 0.07  $\text{cm}^2$  (printed area = 0.5  $\text{cm}^2$ ).<sup>[15]</sup> Herein, the choice of carrying out all measurements on 0.5  $\text{cm}^2$  masked active areas (printed area = 1  $\text{cm}^2$ ) explains the PCE values below 10%: reducing the masked active area from 0.5 to 0.0625  $\text{cm}^2$  boosted the reverse scan PCE from



**Figure 1.** C-PSC used in this work. a) Schematic representation of a typical cell; b) cross-sectional SEM image, showing the different layers of the device; c) EDX elemental maps: Sn (FTO conductive layer), Ti (TiO<sub>2</sub> layer), Zr (insulating ZrO<sub>2</sub> layer), C (graphite/carbon black electrode), Pb and I (infiltrated perovskite throughout the stack).



**Figure 2.** a) PCE distribution of 21 cells, masked to 0.5 cm<sup>2</sup> area, before and after encapsulation; b) typical J-V curves for an encapsulated device with different masked areas. Scans were performed from 1 to -0.1 V at 20 mV s<sup>-1</sup>, in both reverse ( $V_{OC}$  to  $J_{SC}$ ) and forward directions.

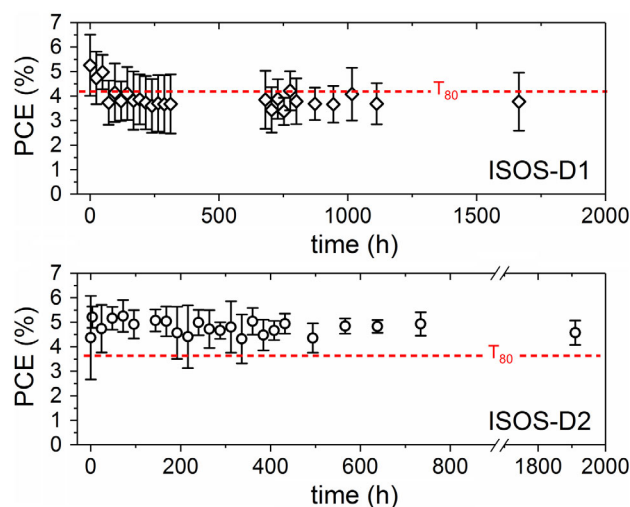
5.6% (5.2% forward scan, 5.4% stabilized at maximum power point—Figure S2, Supporting Information) up to 9.3% (7.7% forward scan), as shown in Figure 2b. As well as for similar cells infiltrated with MAPI,<sup>[20]</sup> the dependence of the performance on the masked area is due to limitations in the conductivity of the carbon layer, affecting the series resistance, thus the FF, as clearly shown by the slope of the  $J$ - $V$  curve around  $V_{OC}$ .  $J_{SC}$  values also depended on the masked area, suggesting a non-homogeneously infiltrated perovskite, possibly hindered by dense carbon flakes.<sup>[39]</sup> Despite the lower performance, 0.5 cm<sup>2</sup> masks were used throughout the study to allow sampling a more representative portion of the devices. Incident photons to current efficiency (IPCE) spectra returned values of integrated  $J_{SC}$  consistent with those obtained by the  $J$ - $V$  scans under the solar simulator (Figure S2, Supporting Information). Encapsulated devices were shipped by air to the other partners for stability assessment and further characterization, as shown in Table 1. Once the cells were received and before conducting stability tests, devices were measured at the characterization laboratory, by performing  $J$ - $V$  scans in reverse and forward directions at the same scan rate as at the manufacturing laboratory, i.e., 20 mV s<sup>-1</sup>. No remarkable degradation due to the shipping time or, in general, to the delay between fabrication by the manufacturing laboratory and testing by the characterization laboratories was observed, as shown in Figure S3, Supporting Information, for the cells used for the ISOS-O2 test in Barcelona (Spain).

**Table 1.** Number of cells shipped to the different partners and tests performed, according to the ISOS definition.

No. of cells	Tests	Laboratory
12	ISOS D1, D2, L1, L2	Bangor University (UK)
2	ISOS O2	ICN2 Barcelona (Spain)
2	ISOS O2	MCAST Paola (Malta)
2	Raman spectroscopy	Swansea University (UK)
2	ISOS L1 (MPPT) and steady-state measurements	University of Rome Tor Vergata (Italy)

## 2.2. Stability Analysis in the Dark (ISOS-D)

In the dark, both at room temperature (ISOS D1) and at 65 °C (ISOS D2), the encapsulated devices proved to be remarkably stable. Interestingly, at room temperature (Figure 3, top), they suffered from an initial loss in performance, primarily due to a decrease in the  $V_{OC}$  (Figure S4, Supporting Information), which led to a drop of around 20% in the initial PCE in 75 h ( $T_{80}$ ), although this stabilized afterward without any further decrease for over 1000 h. By contrast, when subjected to elevated temperature at 65 °C (Figure 3, bottom), the cells experienced a 20% improvement in the average performance within the first 3–4 h; such improvement was then retained for almost 2000 h, without seeing any further drop in performance. In this case though, the  $V_{OC}$  decreased in the first few hours, but this was offset by an



**Figure 3.** Stability analysis on C-PSC devices following ISOS-D1 (dark, room temperature, ambient humidity) and ISOS-D2 (dark, 65 °C, ambient humidity). Average of three cells, 0.5 cm<sup>2</sup> masked area. The dashed line indicates  $T_{80}$  value, i.e., the time when the PCE drops to 80% of its initial value. The remaining PV parameters are reported in Figure S3 and S4, Supporting Information.

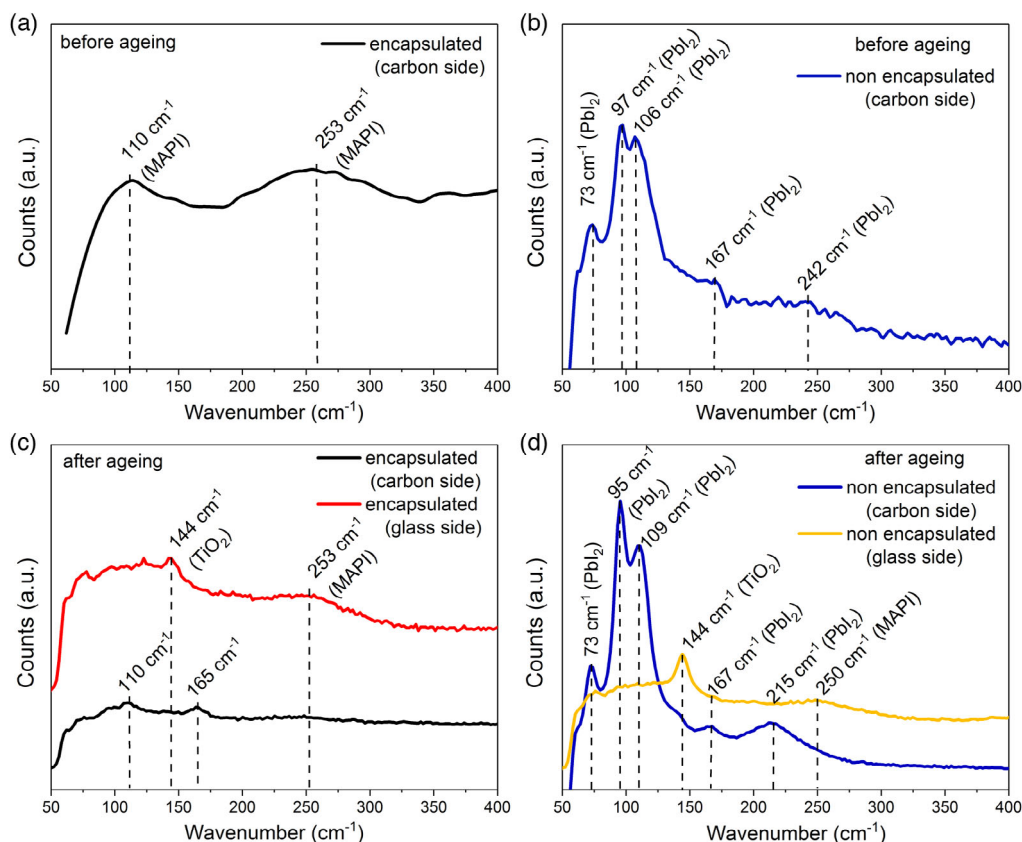
increase in the  $J_{SC}$  (Figure S5, Supporting Information), leading to the overall PCE improvement. AVA-MAPI perovskite for C-PSCs were (in this case) and usually are annealed at low temperature, i.e., 50 °C, thus prolonged exposure to 65 °C led most likely to further annealing of the absorber layer with an improvement of the perovskite crystallinity and/or interfaces quality, i.e., better contact between perovskite and mesoscopic layers.

On the devices aged in the dark, Raman spectroscopy was applied to probe the degradation products within a perovskite device stack. One of the main by-products of perovskite degradation is lead iodide ( $PbI_2$ ), which has a strong Raman signal, when excited with 532 nm laser,<sup>[40]</sup> and such signal intensity is sensitive to the amount of  $PbI_2$  formed in the perovskite, which can then be related to the film and/or device degradation. The  $PbI_2$  peak can be detected as long as sufficient light reaches the  $PbI_2$  formed at the interfaces and/or in the bulk of the perovskite film.

In a carbon-based PSC, the absorber layer is infiltrated all the way through the mesoporous layers. Therefore, the perovskite and degradation products formed within the perovskite can be detected and monitored either from the glass/m-TiO<sub>2</sub> side or from the air/carbon side. The penetration depth of 532 nm laser source into  $CH_3NH_3PbI_3$  active layer is approximately 500 nm, which is much less than the total thickness of the carbon layer (i.e., >10 μm). Thus, the Raman signal from the carbon side will

be indicative of perovskite and  $PbI_2$  formed near the surface of the carbon layer only. On the contrary, measuring the device stack from the glass side will give information about perovskite and degradation products formed in the mesoporous TiO<sub>2</sub> layer only (≈700 nm thick), i.e., in the photoactive part of the stack, where charge carriers are generated.

Raman measurements were thus performed on encapsulated cells, before and after ageing for 1200 h in the dark at room temperature and ambient humidity (ISOS-D1), and on nonencapsulated devices for comparison. The Raman spectra for the fresh encapsulated and nonencapsulated samples measured from the carbon side are shown in **Figure 4a,b**. For the encapsulated sample, typical Raman spectrum of  $CH_3NH_3PbI_3$  is observed with two broad and weak peaks at 110 and 250 cm<sup>-1</sup>, which were assigned to the vibrational and torsional modes of the methyl ammonium (MA) cations, respectively.<sup>[41]</sup> For the nonencapsulated sample, a completely different spectrum is measured, which shows sharp and intense peaks at 73, 96<sup>-</sup>, and 106 cm<sup>-1</sup> indicatives of the presence of a large amount of  $PbI_2$ <sup>[42]</sup> near the carbon surface, along with nondegraded perovskite, as revealed by the broad and poorly resolved peak centered at 242 cm<sup>-1</sup>. Therefore, the perovskite film near the surface of the device has already initiated degradation shortly after fabrication due to exposure to air when the device is not encapsulated because some  $PbI_2$  is formed alongside  $CH_3NH_3PbI_3$ .



**Figure 4.** Raman spectra of C-PSC devices analyzed under ISOS-D1 conditions (dark, room temperature, ambient humidity). a,b) Freshly prepared, before ageing: encapsulated (a) and not encapsulated (b); after c) 1200 h of ageing: encapsulated and d) not encapsulated. Carbon side and glass side refer to the direction the laser hit on the sample, respectively, from the back through the carbon electrode and from the front through the conductive glass.



After aging, different spectra are observed when measuring the devices from the carbon side (Figure 4c,d, black lines). In the case of the encapsulated sample, no  $\text{PbI}_2$  is measured near the surface but two small peaks at  $110$  and  $165\text{ cm}^{-1}$  were observed, which could be due to the formation of dihydrate perovskite  $(\text{CH}_3\text{NH}_3)_4\text{PbI}_6 \cdot 2\text{H}_2\text{O}$ , as shown in an earlier report.<sup>[40]</sup> The presence of dihydrate perovskite suggests that small amount of water could have been trapped in the stack during the fabrication process and/or the encapsulation, both conducted in air. Still the encapsulating glass seems to work as a barrier to environmental moisture and oxygen, preventing further degradation of the perovskite to  $\text{PbI}_2$ . For the nonencapsulated sample, intense  $\text{PbI}_2$  signal is measured from the carbon side, and the perovskite Raman bands are not observed anymore (the additional peak at  $215\text{ cm}^{-1}$  is an overtone of  $109\text{ cm}^{-1}$  peak of  $\text{PbI}_2$  as described by Warren et al.<sup>[42]</sup>). This clearly indicates the conversion of perovskite to  $\text{PbI}_2$  in the carbon layer, near the surface, during the aging process.

By contrast, when the aged samples are measured from the mesoporous  $\text{TiO}_2$  side (Figure 4c,d, red lines),  $\text{PbI}_2$  is not detected for either the encapsulated or the nonencapsulated samples. Instead, the band centered at  $250\text{--}253\text{ cm}^{-1}$  indicates non-degraded perovskite and the peak at  $144\text{ cm}^{-1}$  matches well with anatase  $\text{TiO}_2$ .<sup>[41,43]</sup> The perovskite infiltrated within the mesoporous  $\text{TiO}_2$  layer was well preserved and did not undergo any major degradation, even without encapsulation. This correlates well with the performance of the devices, as shown in Table S1, Supporting Information: there is no degradation of the efficiency after 1200 h of ageing for both the encapsulated and nonencapsulated samples, and even a slight improvement in reverse bias. Indeed, Raman measurements showed that although the perovskite is degraded in the carbon electrode without encapsulation, it remains unchanged in the photoactive layer, where charges are generated (Figure S6, Supporting Information), which explains the good stability in the dark of both the encapsulated and nonencapsulated carbon-based PSC.

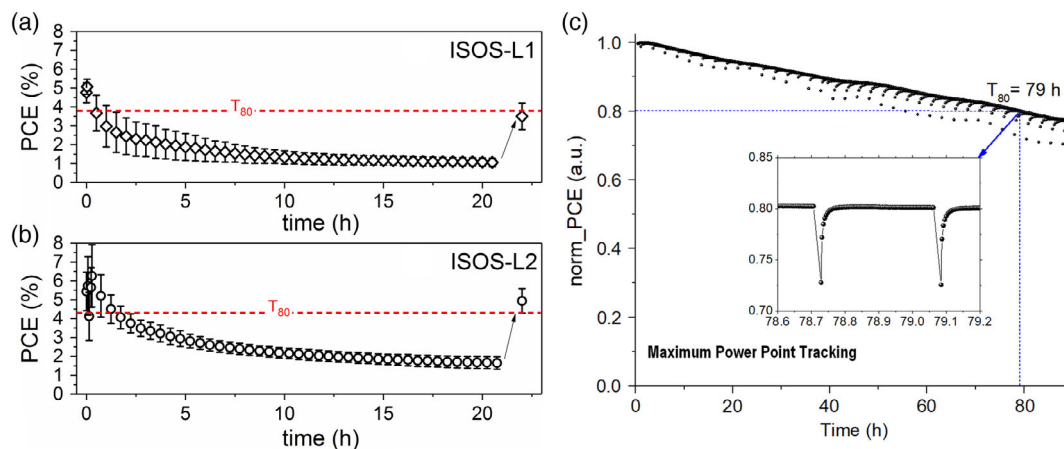
### 2.3. Stability Analysis Under Light Irradiation at 1 sun (ISOS-L)

The high stability observed under ISOS-D1 and D2 conditions was not replicated under continuous illumination at open circuit at room temperature (in accordance with ISOS-L1 tests) nor at  $65\text{ }^\circ\text{C}$  (ISOS-L2): in both instances, the performance dramatically dropped in few hours, regardless the temperature (Figure 5). Cells used for ISOS-L1 and L2 tests were retested 1 month after light-soaking and they did still work, confirming that, also for this cell architecture, storage in the dark for a sufficiently long time can induce performance recovery.<sup>[12,32]</sup> In this case, the recovery was only partial; still, around the 80% of the initial value was regained, due to a slight  $V_{\text{OC}}$  rise coupled to an irreversible  $J_{\text{SC}}$  drop of almost 50%, that, as a consequence, boosted the FF to higher values than at the beginning of the test, mitigating the loss in performance (Figure S7 and S8, Supporting Information).

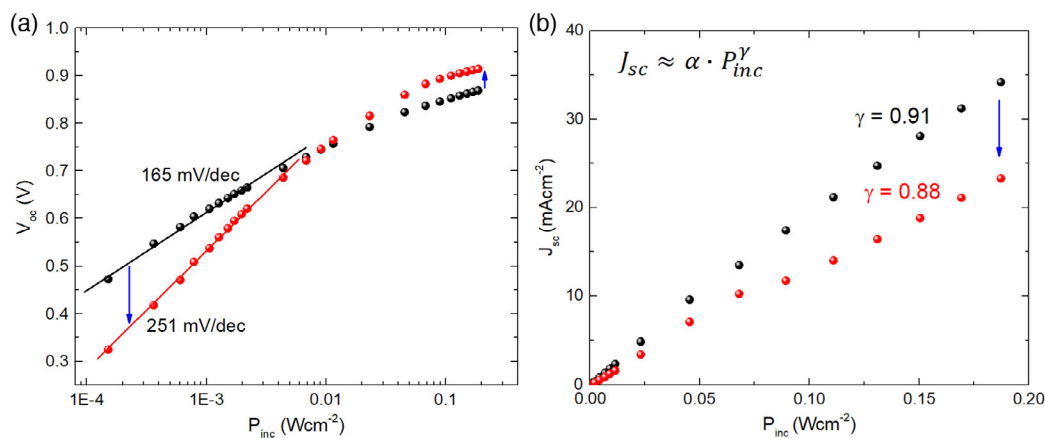
It is well known that an open-circuit bias can accelerate the degradation during light-soaking tests:<sup>[12]</sup> nonextracted photo-generated charges accumulate and lead to high concentrations of radicals, which, in presence of oxygen and light, degrade the device.<sup>[9,28]</sup>

Also, the spectrum from a sulfur plasma lamp is broader than that of white light emitting diodes (LEDs), which do not include ultraviolet (UV) and infrared radiation, limiting the optical excitation to the visible spectrum and thus degradation. Cells were then tested under white LEDs at maximum power point (MPP) by dynamically tracking it with a Perturb & Observe algorithm. The main PV parameters were recorded every 20 min with a  $JV$  scan. Degradation occurred also in this case, but, as expected, at a slower rate than at open circuit, with  $T_{80}$  reached after 79 h (Figure 5c).

The inset shows the MPP dynamic behavior after each  $JV$  scan: the  $JV$  hysteresis directly affects the time required to reach the steady-state MPP. As demonstrated by Pockett et al.<sup>[44]</sup> for similar device structure, the slow response time under



**Figure 5.** Stability tests on encapsulated C-PSCs, following ISOS-L protocols: a,b) 1 sun from sulfur plasma lamp at open circuit, and c) 1 equivalent sun from white LEDs, MMP tracking. (a) ISOS-L1 (room temperature, ambient humidity) and (b) ISOS-L2 ( $65\text{ }^\circ\text{C}$ , ambient humidity). Reported data are averaged values over three devices with  $0.5\text{ cm}^2$  masked area. The cells were tested again once shipped back to the manufacturing laboratory, showing partial recovery. (c) ISOS-L1 (room temperature, ambient humidity) under LEDs at 1 equivalent sun, MMP tracking.



**Figure 6.** Comparison of C-PSC behavior before (black symbols) and after (red symbols) the light soaking under white LED at MPP (ISOS-L1): a)  $V_{OC}$  and b)  $J_{SC}$  at different light intensities.

illumination can be related to the formation of 2D perovskite regions which restrict ion migration, a phenomenon that is promoted by the AVA additive.

The evolution of  $V_{OC}$  and  $J_{SC}$  with light intensity ( $P_{inc}$ ) can provide information about the recombination phenomena within the device. **Figure 6** shows semilogarithmic plots of the  $V_{OC}$  versus light intensity for the C-PSC before and after light-soaking at MPP. At low light levels ( $<0.01 \text{ W cm}^{-2}$ ), the aged devices show an increased slope of the  $V_{OC}$  (from 165 to 251  $\text{mV dec}^{-1}$ ), in particular, as demonstrated by Gouda et al.,<sup>[45]</sup> at these irradiation levels the increase in  $V_{OC}$  is limited by the  $\text{TiO}_2$  and the accumulation of the photoinjected electrons, similar to dye-sensitized solar cells. This is a clear indication of a severe photoinduced degradation of the mesoporous layer.

Additional information about recombination processes can be extrapolated by the power law fit of the  $J_{SC}$  trend at different light intensities, before and after the stability test. The reduction of the power index ( $\gamma$ ) from 0.91 to 0.88 is an evident indication of the appearance of bimolecular recombination processes induced by the light stress that degrades the charge collection capability.<sup>[46]</sup>

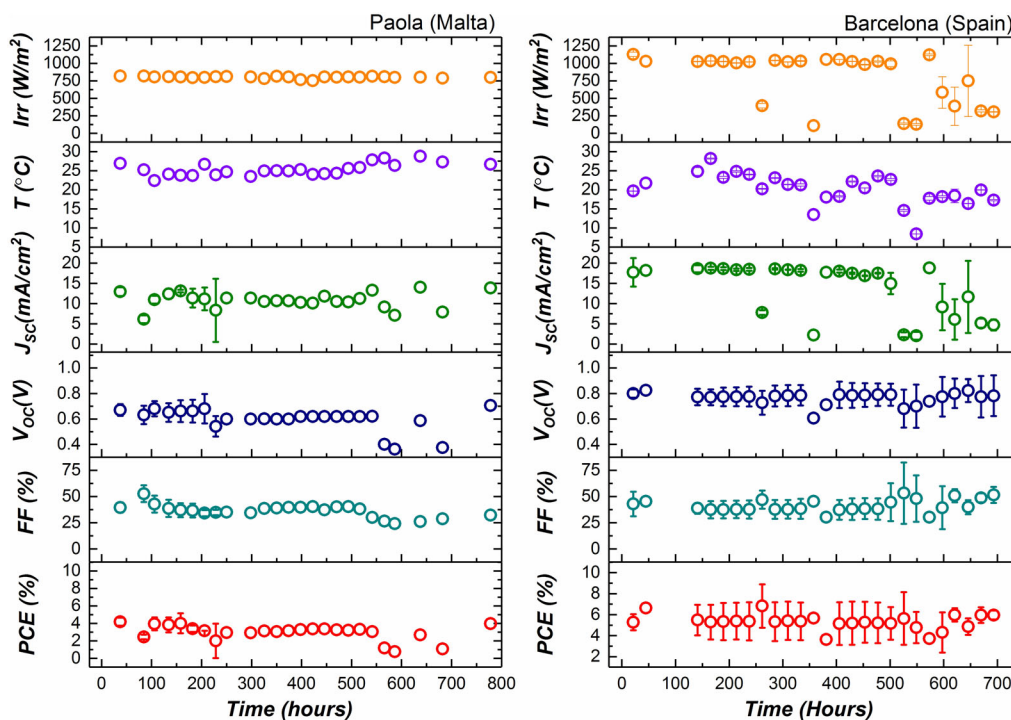
## 2.4. Stability Analysis Outdoors (ISOS-O)

Outdoor measurements were carried out in two different sites, i.e., Barcelona, Spain ( $41^\circ 30' 5.56'' \text{ N}$ ,  $2^\circ 6' 39.68'' \text{ W}$ ) and Paola, Malta ( $35^\circ 52' 53.04'' \text{ N}$ ,  $14^\circ 30' 42.26'' \text{ E}$ ), accordingly to the ISOS-O2 protocol, i.e., by performing  $J$ - $V$  scans in situ under natural illumination. It is worth noting that while in Barcelona the testing system available was a 2-axis tracking one, in Malta it was fixed, both allowed by the ISOS protocols. For standard operating procedures, internal and specific to each laboratory, UV filters were used in Barcelona but not in Malta. Nevertheless, in both locations, as shown in **Figure 7**, cells were stable for several weeks (between 700 and 800 h, i.e., around 30 days). Cells were still working when data collection ended, and IPCE spectra were remeasured indoors: little variation is observed compared with the spectrum at the beginning of the test (Figure S9, Supporting Information). These stability

measurements add further evidence of the good outdoor performance of this PSC architecture to previously published reports by other groups of 1-week stability in Jeddah, Saudi Arabia,<sup>[47]</sup> 30 days in Wuhan, China,<sup>[19]</sup> and nearly 90 days in location near Beijing, China, with temperatures ranging between  $-10$  and  $35^\circ \text{C}$ .<sup>[29]</sup>

As the tests were conducted between April and June (late spring–summer at the given latitudes) in Southern Europe, temperatures were above  $20^\circ \text{C}$  during the central hours of the day and above  $6^\circ \text{C}$  at night, whereas irradiation levels peaked near  $1000 \text{ W m}^{-2}$  were achieved around midday in sunny days. Irradiance levels dropped during cloudy days and so did the photo-generated current, but overall, the performance was not affected, as the detrimental effect on  $J_{SC}$  was offset by the FF improvement.

Although **Figure 7** shows only midday values of the recorded temperature, irradiance, and PV parameters, in one site (Barcelona), C-PSC outdoor operation was also tracked from early morning to late evening, making possible single-day analysis of the device response under variable irradiation levels and temperatures.  $J$ - $V$  curves were performed every 45 min, at a scan rate of  $20 \text{ mV s}^{-1}$  in both forward and reverse direction. The evolution of all the parameters over 3 days, from around 8:00 a.m. to around 8:00 p.m., is shown in **Figure 8**. Temperatures were lower in the morning, high and quite constant in the central hours, and still around  $20^\circ \text{C}$  even in the late evening. The  $J_{SC}$  trend mimicked the evolution of the irradiation and  $V_{OC}$  was fairly constant over the hours, with a slight drop at about 8 am and 8 pm. Large FF values were observed in the early morning and late evening, whereas they significantly dropped in the central hours when the temperature and irradiation were around their maximum: the high series resistance of the carbon electrode affected the FF as the irradiation levels and the photo-generated currents increased, limiting the PCE in the central hours of the day. Temperature and variable spectral composition of sunlight during the day could explain the asymmetrical PCE trend, with the highest values in the late evening. It is worth noting that a similar behavior (higher PCE values at the beginning and end of the day) has been reported also for  $\text{NiOx}/\text{MAPI}/\text{PCBM}$ <sup>[48]</sup> and  $\text{m-TiO}_2/\text{mixed cation-halide perovskite}/\text{spiro}$ <sup>[30]</sup> devices.



**Figure 7.** Stability analysis conducted on encapsulated C-PSCs according to protocol ISOS-O2 (outdoor tests): irradiance, temperature, and PV parameters over time for cells tested in Paola, Malta (left, May–June) and Barcelona, Spain (right, April–May). In each location, two devices were tested (in Paola, one cell stopped working after 250 h). Plotted data refer to midday measurements. UV filters and a 2-axis tracking system were used for the cells tested in Barcelona. A fixed system and no UV filters were used for the cells tested in Malta.

As for other PSC architectures, the response of these C-PSC devices in terms of stability depends on the applied ageing conditions and can be explained by the different types of degradation, i.e., reversible or permanent, that are triggered in each case. As previously reported for mixed cation–halide perovskites on both  $m\text{-TiO}_2$ - and  $\text{SnO}_2$ -based cells,<sup>[30,32,49]</sup> this work demonstrates that printable C-PSC cells can degrade beyond the threshold of reversible losses under continuous illumination (faster at open circuit than when tracking the maximum power point) and have their efficiency dropping quickly, even if a partial recovery is possible upon a long enough time of storage in the dark, whereas, over light/dark cycles such as in an outdoor test, the degradation can be reversible and cells recover overnight, leading to a remarkable  $\approx 30$  days stable operation in two different sites.

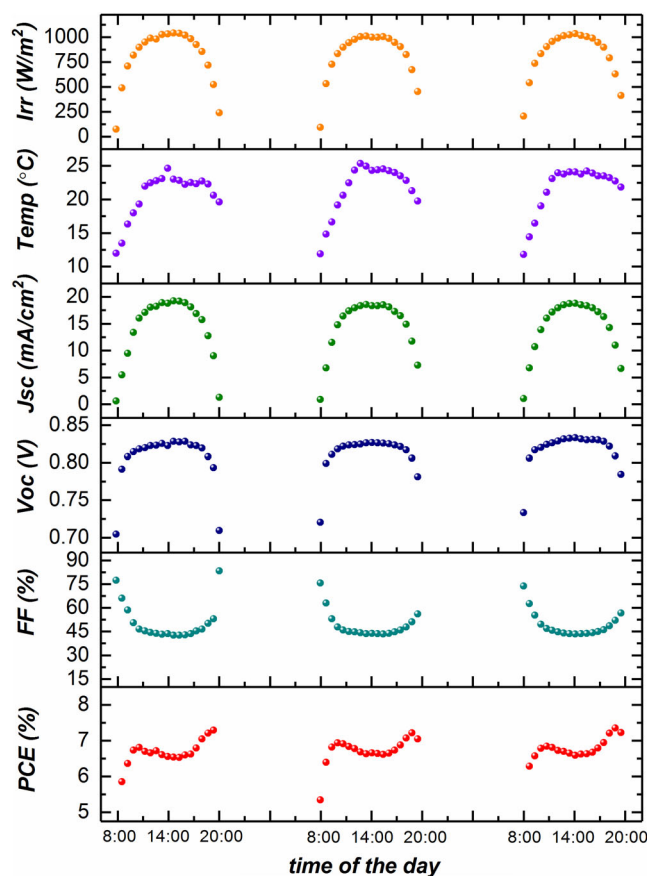
### 3. Conclusion

We have conducted an interlaboratory stability analyses of C-PSCs fabricated under controlled conditions by different laboratories. Analyses were performed following several ISOS protocols (ISOS-D1, D2, L1, L2, O2), applied by different laboratories to assess the stability of printed, HTM-free carbon-based PSC cells based on a triple mesoscopic stack with a carbon back electrode. While showing over 1000 h stability in the dark at both room temperature and  $65^\circ\text{C}$ , these devices suffered notable performance drop when tested under continuous illumination in open-circuit conditions. Maximum power point tracking and

LED illumination resulted in slower degradation, as already demonstrated for other PSC architecture. Finally, cells diurnal outdoor operation was tracked for several days, showing higher PCE values in the early morning and late evening and a drop in the central hours of the day, due to the high series resistance of the carbon electrode that limits the FF. Nonetheless, devices were stable for about 30 days of outdoor operation in two different sites, confirming that, for this architecture, the natural day/night cycling, i.e., real-world conditions, is beneficial to the long-term operation and it is a more realistic approach to assessing the stability and lifetime for C-PSC devices. As light/dark cycles can be reproduced also indoors, they should be included in long-term stability studies, as agreed on in the new ISOS protocols.<sup>[38]</sup>

### 4. Experimental Section

**Cells Fabrication:** FTO glass substrates (TEC7, XOP) were etched using a Rofin Nd:YVO<sub>4</sub> laser (532 nm) at a speed of  $150\text{ mm s}^{-1}$ , cleaned with Hellmanex solution in deionized water, washed with deionized water and rinsed in acetone and isopropanol, before being O<sub>2</sub> plasma treated. A 50 nm-thick compact TiO<sub>2</sub> layer was deposited via spray pyrolysis at  $300^\circ\text{C}$  from a solution 1:9 of titanium di-isopropoxide bis(acetylacetonate) (Sigma) in isopropanol. The triple mesoporous stack was obtained via screen printing of commercial pastes: first, the TiO<sub>2</sub> layer (30 NRD Dyesol, diluted 1:1 by weight with terpineol), followed by sintering at  $550^\circ\text{C}$  for 30 min; then the ZrO<sub>2</sub> layer (Solaronix), sintered at  $400^\circ\text{C}$  for 30 min; finally, the carbon layer (Gwent Electronic Materials), sintered at  $400^\circ\text{C}$  for 30 min. A solution of AVAl, MAI, and PbI<sub>2</sub> in gamma-butyrolactone (GBL) was prepared according to Jiang et al.<sup>[50]</sup> infiltrated



**Figure 8.** Stability analysis according to protocol ISOS-O2 (outdoor tests): evolution of irradiance, temperature, and PV parameters during daytime over three consecutive days for an encapsulated solar cell monitored in Barcelona, Spain.

from the top carbon electrode, percolated throughout the mesoporous stack down to the TiO<sub>2</sub>, filling the pores and, within them, slowly crystallizing into perovskite during the annealing at 50 °C for 1 h.

Silver paint was applied to the contacts and a black tape mask to the glass side, with an aperture of 0.5 cm<sup>2</sup> to univocally define the active area, allowing consistency for samples measured in different laboratories. All cells were encapsulated in air using a plain glass cover and a UV-curable epoxy for edge sealing (primary encapsulation). Curing was performed under a UV lamp for few seconds, having care of exposing only the epoxy around the glass cover edges. Cells meant for outdoor testing had wires ultrasonically soldered to the contacts to make possible the addition of a UV filter and a secondary encapsulation of waterproof silicone (Figure S10, Supporting Information).

**Indoor ISOS Tests:** Prior to shipping, the cells were characterized at the manufacturer laboratory. *JV* measurements were performed using in-house developed software and a Keithley 2400 source meter under a class AAA solar simulator (Newport Oriel Sol3A equipped with a sulfur plasma lamp) at AM1.5 illumination conditions calibrated at 1 sun against a KG5 filtered silicon reference cell (Newport Oriel 91150-KG5). The cells were scanned in reverse (from *V*<sub>OC</sub> to *J*<sub>SC</sub>) and forward directions at a scan rate of 20 mV s<sup>-1</sup>. For the stabilized measurements, a bias, set to the voltage at maximum power point as determined by the *JV* sweep, was applied and the current monitored under illumination. The active area of solar cells was defined through a laser-cut mask with an open area of 0.5 cm<sup>2</sup>. IPCE spectra were collected using a QE X10 spectral response machine in the 300–850 nm wavelength range. Once received by the characterization laboratory and before starting the stability tests, they were measured again,

using the same settings as in the manufacturing laboratory: 20 mV s<sup>-1</sup>, for both reverse and forward scans between 1 and -0.1 V.

Dark and thermal stress tests (ISOS-D1, ISOS-D2) were conducted using a Weiss Technik UK thermal-humidity chamber. Light soaking tests (ISOS-L1, ISOS-L2) were conducted using a sulfur plasma lamp (class AAA) from Plasma-1 in Germany with temperature-controlled stage. Irradiance levels were calibrated using a thermopile every 5 days. Current-voltage and maximum power point tracking (MPPT) were conducted using a Keithley 2601.

MPPT was performed using the commercial apparatus ARKEO (Cicci Research). The main PV parameters were recorded every 20 min with an *I-V* scan. The maximum power point was dynamically tracked with a Perturb & Observe algorithm.

**Outdoor ISOS Tests in Barcelona (Spain):** Upon receipt of cells, *JV* curves were measured indoors under a metal halide solar simulator lamp (AM1.5G) and IPCE measurements were taken from 300 to 800 nm, both before and after the addition of a UV filter. Outdoor stability measurements were conducted on the encapsulated cells with UV filters and masks, using a 2-axis tracking system, and recording forward and reverse *J-V* curves (sweep rate 20 mV s<sup>-1</sup>), temperature, and irradiance every ≈45 min, when solar irradiance exceeded 50 W m<sup>-2</sup> as measured by the pyranometer on the solar tracker. Between measurements and when irradiance was below 50 W m<sup>-2</sup> cells were held at open circuit. Cells were remeasured in the lab after 30 days of outdoor measurements.

**Outdoor ISOS Tests in Paola (Malta):** Outdoor stability measurements were conducted on the encapsulated cells without UV filters and masks, using a fixed system with orientation 35° South, and recording forward and reverse *J-V* curves (sweep rate 20 mV s<sup>-1</sup>), temperature, and irradiance every ≈30 min, when solar irradiance is approximately 800 W m<sup>-2</sup> as measured by the pyranometer on the surface. Between measurements and when irradiance was below 800 W m<sup>-2</sup> cells were held at open circuit.

**Further Characterization:** Morphology and thickness of the mesoporous stack was studied using a JEOL-JSM-7800F field emission scanning electron microscope (5 kV acceleration voltage, a working distance of 10 mm, and a magnification of 25 000×). EDX mapping was used to determine the element distribution using 20 kV acceleration voltage.

Raman measurements were performed with a Renishaw Invia Raman system in backscattering configuration. A 532 nm laser and 50× objective were used (Numerical Aperture: 0.50, spot size ≈1 μm). A laser power of 0.3 mW and acquisition time of 5 s were used. For each sample, 100 different spots were measured over the surface and averaged to increase the signal-to-noise ratio without degrading the cell by long laser exposure. The samples were analyzed from both the carbon side and glass side to probe the perovskite degradation in the carbon or mesoporous TiO<sub>2</sub> film, respectively.

Light intensity-dependent tests were performed using the commercial apparatus ARKEO (Cicci Research) endowed with a LED-based illuminator (spectral emission from 450 to 750 nm) with 2 cm diameter of optical aperture. Devices were attached over a metal substrate to increase the thermal capacitance. No thermal control was applied to the device because the temperature variation was confined between 24 and 34 °C.

## Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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## Conflict of Interest

The authors declare no conflict of interest.

## Keywords

carbon, interlaboratory studies, ISOS protocols, long-term stability, perovskite solar cells

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